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### **Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems**

**Embedded - System On Chip (SoC)** refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

### **What are Embedded - System On Chip (SoC)?**

**System On Chip (SoC)** integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

#### **Details**

Product Status	Active
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	256KB
RAM Size	64KB
Peripherals	DDR, PCIe, SERDES
Connectivity	CANbus, Ethernet, I²C, SPI, UART/USART, USB
Speed	166MHz
Primary Attributes	FPGA - 10K Logic Modules
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	400-LFBGA
Supplier Device Package	400-VFBGA (17x17)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/m2s010-vf400i">https://www.e-xfl.com/product-detail/microchip-technology/m2s010-vf400i</a>

# Figures

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Figure 1	High Temperature Data Retention (HTR) .....	9
Figure 2	Timing Model .....	15
Figure 3	Input Buffer AC Loading .....	17
Figure 4	Output Buffer AC Loading .....	18
Figure 5	Tristate Buffer for Enable Path Test Point .....	19
Figure 6	Timing Model for Input Register .....	65
Figure 7	I/O Register Input Timing Diagram .....	66
Figure 8	Timing Model for Output/Enable Register .....	68
Figure 9	I/O Register Output Timing Diagram .....	69
Figure 10	Input DDR Module .....	70
Figure 11	Input DDR Timing Diagram .....	71
Figure 12	Output DDR Module .....	73
Figure 13	Output DDR Timing Diagram .....	74
Figure 14	LUT-4 .....	75
Figure 15	Sequential Module .....	76
Figure 16	Sequential Module Timing Diagram .....	77
Figure 17	Power-up to Functional Timing Diagram for SmartFusion2 .....	115
Figure 18	Power-up to Functional Timing Diagram for IGLOO2 .....	116
Figure 19	DEVRST_N to Functional Timing Diagram for SmartFusion2 .....	117
Figure 20	DEVRST_N to Functional Timing Diagram for IGLOO2 .....	119
Figure 21	I2C Timing Parameter Definition .....	125
Figure 22	SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1) .....	128
Figure 23	SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1) .....	131

## 2 IGLOO2 FPGA and SmartFusion2 SoC FPGA

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Microsemi's mainstream SmartFusion®2 SoC and IGLOO®2 FPGA families integrate an industry standard 4-input lookup table-based (LUT) FPGA fabric with integrated math blocks, multiple embedded memory blocks, and high-performance SerDes communication interfaces on a single chip. Both families benefit from low-power flash technology and are the most secure and reliable FPGAs in the industry. These next generation devices offer up to 150K Logic Elements, up to 5 MBs of embedded RAM, up to 16 SerDes lanes, and up to four PCI Express Gen 2 endpoints, as well as integrated hard DDR3 memory controllers with error correction.

SmartFusion2 devices integrate an entire low-power, real-time microcontroller subsystem (MSS) with a rich set of industry-standard peripherals including Ethernet, USB, and CAN, while IGLOO2 devices integrate a high-performance memory subsystem with on-chip flash, 32 Kbyte embedded SRAM, and multiple DMA controllers.

### 2.1 Device Status

The following table shows the design security densities and development status of the IGLOO2 FPGA and SmartFusion2 SoC FPGA devices.

**Table 1 • IGLOO2 and SmartFusion2 Design Security Densities**

Design Security Device Densities	Status
005	Production
010, 010T	Production
025, 025T	Production
050, 050T	Production
060, 060T	Production
090, 090T	Production
150, 150T	Production

The following table shows the data security densities and development status of the IGLOO2 FPGA and SmartFusion2 SoC FPGA devices.

**Table 2 • IGLOO2 and SmartFusion2 Data Security Densities**

Data Security Device Densities	Status
005S	Production
010TS	Production
025TS	Production
050TS	Production
060TS	Production
090TS	Production
150TS	Production

## 2.3.2 Power Consumption

The following sections describe the power consumptions of the devices.

### 2.3.2.1 Quiescent Supply Current

**Table 10 • Quiescent Supply Current Characteristics**

Power Supplies/Blocks	Modes and Configurations	
	Non-Flash*Freeze	Flash*Freeze
FPGA Core	On	Off
V <sub>DD</sub> /SERDES_[01]_VDD <sup>1</sup>	On	On
V <sub>PP</sub> /V <sub>PPNVM</sub>	On	On
HPMS_MDDR_PLL_VDDA/FDDR_PLL_VDDA/ CCC_XX[01]_PLL_VDDA/PLL0_PLL1_HPMs_MDDR_VDD A	0 V	0 V
SERDES_[01]_PLL_VDDA <sup>2</sup>	0 V	0 V
SERDES_[01]_L[0123]_VDDAPLL/VDD_2V5 <sup>2</sup>	On	On
SERDES_[01]_L[0123]_VDDAIIO <sup>2</sup>	On	On
V <sub>DDI</sub> <sup>3, 4</sup>	On	On
V <sub>REF</sub> <sub>x</sub>	On	On
MSSDDR CLK	32 kHz	32 kHz
RAM	On	Sleep state
System controller	50 MHz	50 MHz
50 MHz oscillator (enable/disable)	Enable	Disabled
1 MHz oscillator (enable/disable)	Disabled	Disabled
Crystal oscillator (enable/disable)	Disabled	Disabled

1. SERDES\_[01]\_VDD Power Supply is shorted to V<sub>DD</sub>.
2. SerDes and DDR blocks to be unused.
3. V<sub>DDI</sub> has been set to ON for test conditions as described. Banks on the east side should always be powered with the appropriate V<sub>DDI</sub> bank supplies. For details on bank power supplies, see “Recommendation for Unused Bank Supplies” table in the [AC393: SmartFusion2 and IGLOO2 Board Design Guidelines Application Note](#).
4. No Differential (that is to say, LVDS) I/Os or ODT attributes to be used.

**Table 11 • SmartFusion2 and IGLOO2 Quiescent Supply Current (V<sub>DD</sub> = 1.2 V) – Typical Process**

Symbol	Modes	005	010	025	050	060	090	150	Unit	Conditions
IDC1	Non-Flash*Freeze	6.2	6.9	8.9	13.1	15.3	15.4	27.5	mA	Typical (T <sub>J</sub> = 25 °C)
		24.0	28.4	40.6	67.8	80.6	81.4	144.7	mA	Commercial (T <sub>J</sub> = 85 °C)
		35.2	41.9	60.5	102.1	121.4	122.6	219.1	mA	Industrial (T <sub>J</sub> = 100 °C)

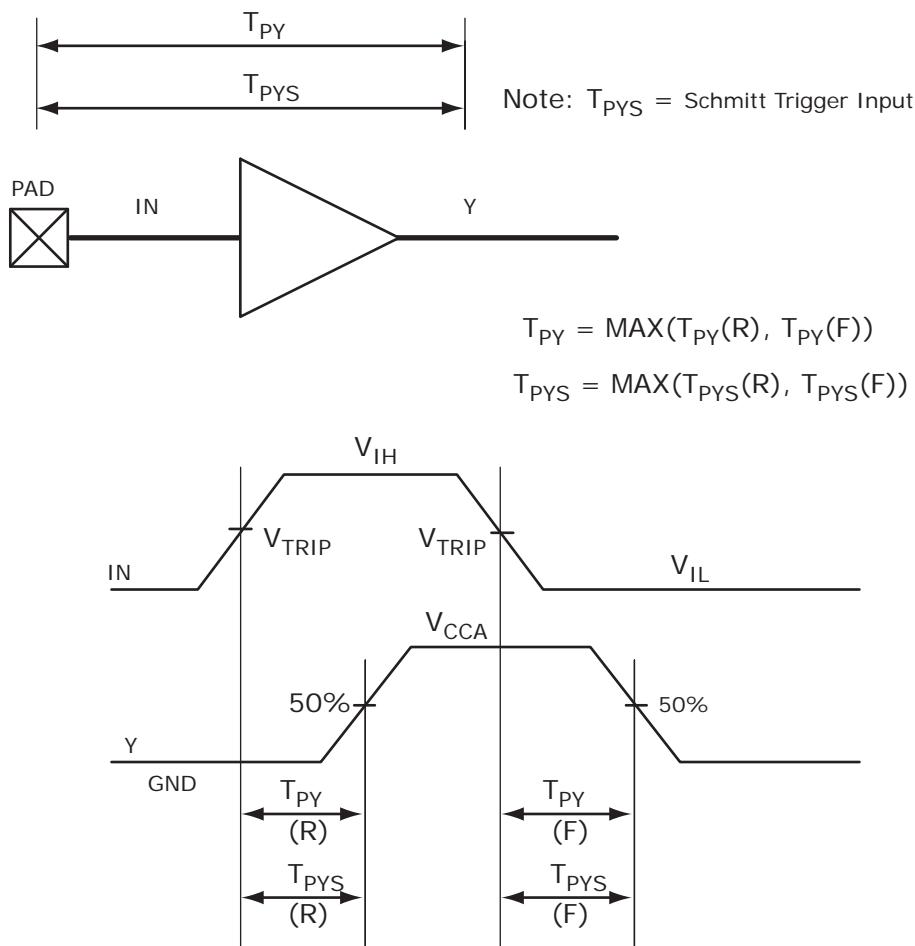
## 2.3.5 User I/O Characteristics

There are three types of I/Os supported in the IGLOO2 FPGA and SmartFusion2 SoC FPGA families: MSIO, MSIOD, and DDRIO I/O banks. The I/O standards supported by the different I/O banks is described in the I/Os section of the [UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide](#).

### 2.3.5.1 Input Buffer and AC Loading

The following figure shows the input buffer and AC loading.

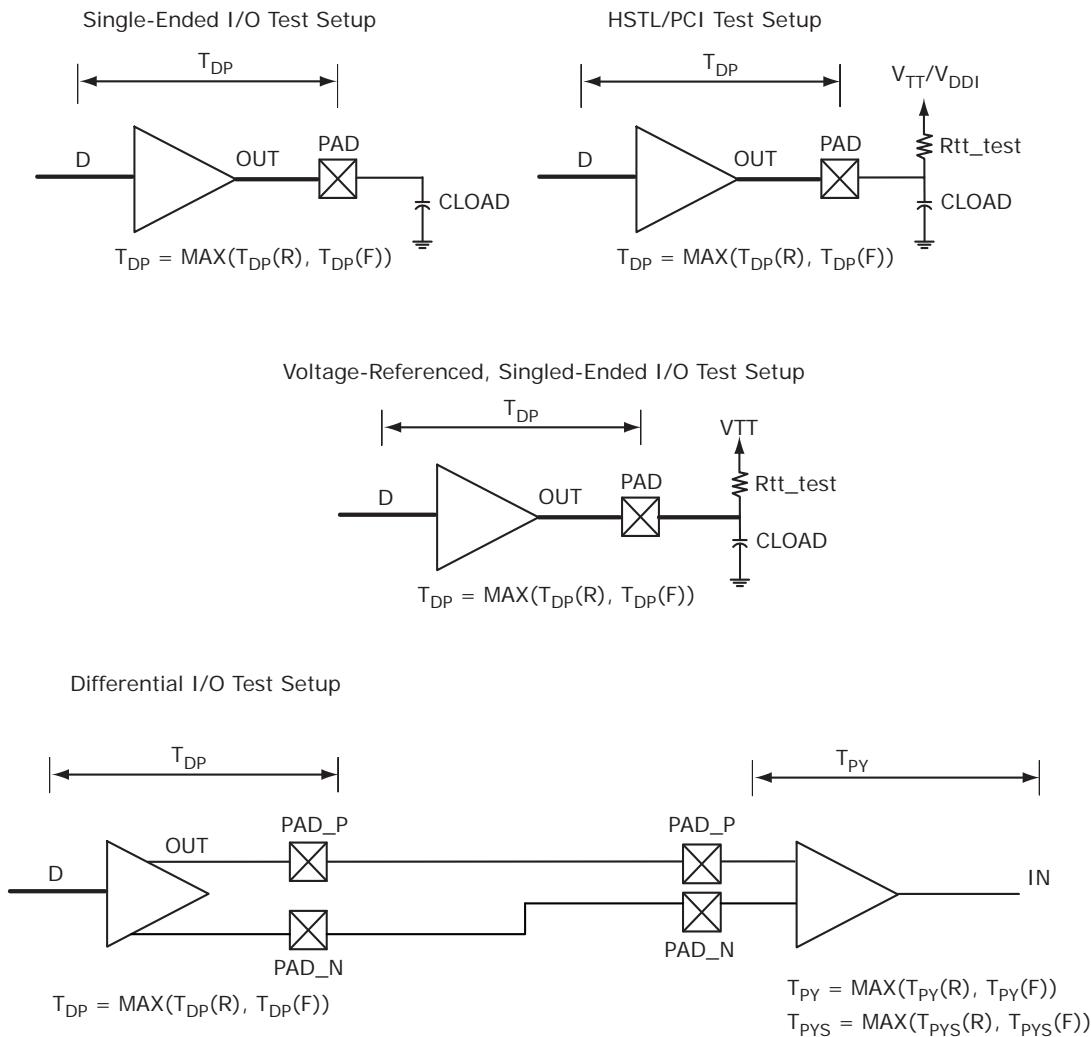
**Figure 3 • Input Buffer AC Loading**



### 2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

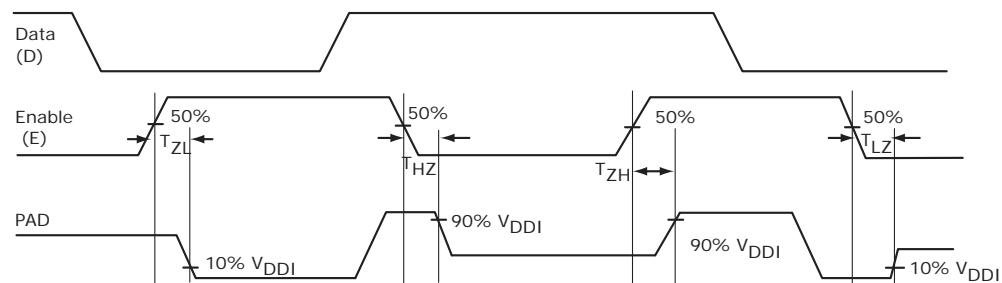
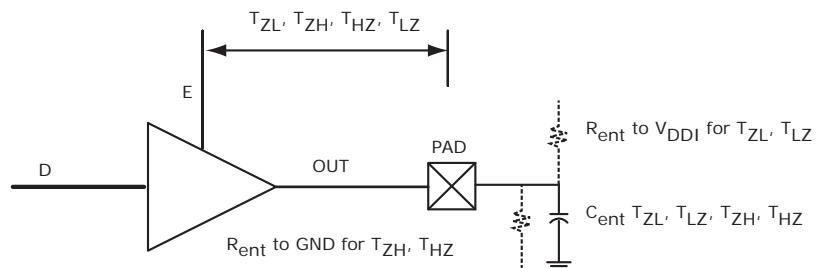
**Figure 4 • Output Buffer AC Loading**



### 2.3.5.3 Tristate Buffer and AC Loading

The tristate path for enable path loadings is described in the respective specifications. The following figure shows the methodology of characterization illustrated by the enable path test point.

**Figure 5 • Tristate Buffer for Enable Path Test Point**



### 2.3.5.4 I/O Speeds

This section describes the maximum data rate summary of I/O in worst-case industrial conditions. See the individual I/O standards for operating conditions.

**Table 18 • Maximum Data Rate Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions**

I/O	MSIO	MSIOD	DDRIO	Unit
PCI 3.3 V	630			Mbps
LVTTL 3.3 V	600			Mbps
LVCMS 3.3 V	600			Mbps
LVCMS 2.5 V	410	420	400	Mbps
LVCMS 1.8 V	295	400	400	Mbps
LVCMS 1.5 V	160	220	235	Mbps
LVCMS 1.2 V	120	160	200	Mbps
LPDDR-LVCMS 1.8 V mode			400	Mbps

**Table 128 • DDR2/SSTL18 Transmitter Characteristics (Output and Tristate Buffers)**

	T <sub>DP</sub>		T <sub>ZL</sub>		T <sub>ZH</sub>		T <sub>HZ</sub>		T <sub>LZ</sub>		Unit
	-1	-Std									
<b>SSTL18 Class I (for DDRIO I/O Bank)</b>											
Single-ended	2.383	2.804	2.23	2.623	2.229	2.622	2.202	2.591	2.201	2.59	ns
Differential	2.413	2.84	2.797	3.29	2.797	3.29	2.282	2.685	2.282	2.685	ns
<b>SSTL18 Class II (for DDRIO I/O Bank)</b>											
Single-ended	2.281	2.683	2.196	2.584	2.195	2.583	2.171	2.555	2.17	2.554	ns
Differential	2.315	2.724	2.698	3.173	2.698	3.173	2.242	2.639	2.242	2.639	ns

**2.3.6.5 Stub-Series Terminated Logic 1.5 V (SSTL15)**

SSTL15 Class I and Class II are supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs, and also comply with the reduced and full drive double data rate (DDR3) standard. IGLOO2 FPGA and SmartFusion2 SoC FPGA I/Os supports both standards for single-ended signaling and differential signaling for SSTL18. This standard requires a differential amplifier input buffer and a push-pull output buffer.

**Minimum and Maximum DC/AC Input and Output Levels Specification**

The following table lists the SSTL15 DC voltage specifications for DDRIO bank.

**Table 129 • SSTL15 DC Recommended DC Operating Conditions (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V <sub>DDI</sub>	1.425	1.5	1.575	V
Termination voltage	V <sub>TT</sub>	0.698	0.750	0.803	V
Input reference voltage	V <sub>REF</sub>	0.698	0.750	0.803	V

**Table 130 • SSTL15 DC Input Voltage Specification (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Max	Unit
DC input logic high	V <sub>IH</sub> (DC)	V <sub>REF</sub> + 0.1	1.575	V
DC input logic low	V <sub>IL</sub> (DC)	-0.3	V <sub>REF</sub> - 0.1	V
Input current high <sup>1</sup>	I <sub>IH</sub> (DC)			
Input current low <sup>1</sup>	I <sub>IL</sub> (DC)			

1. See Table 24, page 22.

**Table 131 • SSTL15 DC Output Voltage Specification (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Max	Unit
<b>DDR3/SSTL15 Class I (DDR3 Reduced Drive)</b>				
DC output logic high	$V_{OH}$	$0.8 \times V_{DDI}$		V
DC output logic low	$V_{OL}$		$0.2 \times V_{DDI}$	V
Output minimum source DC current	$I_{OH}$ at $V_{OH}$	6.5		mA
Output minimum sink current	$I_{OL}$ at $V_{OL}$	-6.5		mA
<b>DDR3/SSTL15 Class II (DDR3 Full Drive)</b>				
DC output logic high	$V_{OH}$	$0.8 \times V_{DDI}$		V
DC output logic low	$V_{OL}$		$0.2 \times V_{DDI}$	V
Output minimum source DC current	$I_{OH}$ at $V_{OH}$	7.6		mA
Output minimum sink current	$I_{OL}$ at $V_{OL}$	-7.6		mA

**Table 132 • SSTL15 DC Differential Voltage Specification (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Unit
DC input differential voltage	$V_{ID}$	0.2	V

**Note:** To meet JEDEC electrical compliance, use DDR3 full drive transmitter.

**Table 133 • SSTL15 AC SSTL15 Minimum and Maximum AC Switching Speed (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Max	Unit
AC input differential voltage	$V_{DIFF}$ (AC)	0.3		V
AC differential cross point voltage	$V_x$ (AC)	$0.5 \times V_{DDI} - 0.150$	$0.5 \times V_{DDI} + 0.150$	V

**Table 134 • SSTL15 Minimum and Maximum AC Switching Speed (for DDRIO I/O Bank Only)**

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate	$D_{MAX}$	667	Mbps	AC loading: per JEDEC specifications

**Table 135 • SSTL15 AC Calibrated Impedance Option (for DDRIO I/O Bank Only)**

Parameter	Symbol	Typ	Unit	Conditions
Supported output driver calibrated impedance	$R_{REF}$	34, 40	$\Omega$	Reference resistor = 240 $\Omega$
Effective impedance value (ODT)	$R_{TT}$	20, 30, 40, 60, 120	$\Omega$	Reference resistor = 240 $\Omega$

**Table 168 • LVDS25 Receiver Characteristics for MSIOD I/O Bank (Input Buffers)**

On-Die Termination (ODT)	T <sub>PY</sub>			Unit
	-1	-Std	Unit	
None	2.554	3.004	ns	
100	2.549	2.999	ns	

**Table 169 • LVDS25 Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)**

T <sub>DP</sub>	T <sub>ZL</sub>			T <sub>ZH</sub>			T <sub>HZ</sub>			T <sub>LZ</sub>			Unit
	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	
2.136	2.513	2.416	2.842	2.402	2.825	2.423	2.85	2.409	2.833	2.409	2.833	ns	

**Table 170 • LVDS25 Transmitter Characteristics for MSIOD I/O Bank (Output and Tristate Buffers)**

	T <sub>DP</sub>			T <sub>ZL</sub>			T <sub>ZH</sub>			T <sub>HZ</sub>			T <sub>LZ</sub>			Unit
	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	
No pre-emphasis	1.61	1.893	1.749	2.058	1.735	2.041	1.897	2.231	1.866	2.195	ns					
Min pre-emphasis	1.527	1.796	1.757	2.067	1.744	2.052	1.905	2.241	1.876	2.207	ns					
Med pre-emphasis	1.496	1.76	1.765	2.077	1.751	2.06	1.914	2.252	1.884	2.216	ns					

**LVDS33 AC Switching Characteristics****Table 171 • LVDS33 Receiver Characteristics for MSIO I/O Bank (Input Buffers)**

On Die Termination (ODT)	T <sub>PY</sub>			Unit
	-1	-Std	Unit	
None	2.572	3.025	ns	
100	2.569	3.023	ns	

**Table 172 • LVDS33 Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)**

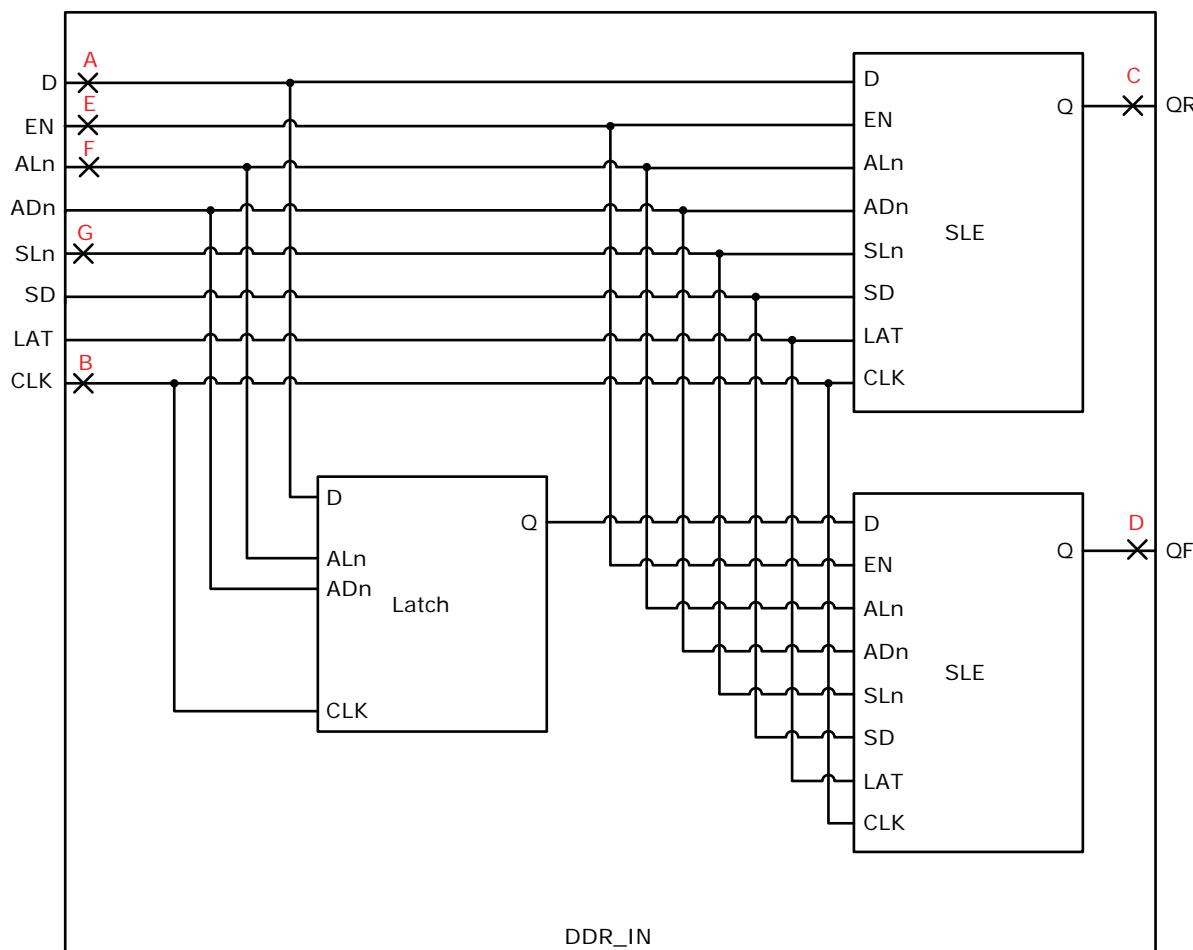
T <sub>DP</sub>	T <sub>ZL</sub>			T <sub>ZH</sub>			T <sub>HZ</sub>			T <sub>LZ</sub>			Unit
	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	
1.942	2.284	1.98	2.33	1.97	2.318	1.953	2.298	1.96	2.307	1.96	2.307	ns	

### 2.3.9 DDR Module Specification

This section describes input and output DDR module and timing specifications.

#### 2.3.9.1 Input DDR Module

Figure 10 • Input DDR Module



The following table lists the 010 device global resources in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 229 • 010 Device Global Resource**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>		<b>Unit</b>
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>	
Input low delay for global clock	$T_{RCKL}$	0.626	0.669	0.627	0.668	ns
Input high delay for global clock	$T_{RCKH}$	1.112	1.182	1.308	1.393	ns
Maximum skew for global clock	$T_{RCKSW}$		0.07		0.085	ns

The following table lists the 005 device global resources in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 230 • 005 Device Global Resource**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>		<b>Unit</b>
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>	
Input low delay for global clock	$T_{RCKL}$	0.625	0.66	0.628	0.66	ns
Input high delay for global clock	$T_{RCKH}$	1.126	1.187	1.325	1.397	ns
Maximum skew for global clock	$T_{RCKSW}$		0.061		0.072	ns

## 2.3.12 FPGA Fabric SRAM

See *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide* for more information.

### 2.3.12.1 FPGA Fabric Large SRAM (LSRAM)

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 1K × 18 in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 231 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 1K × 18**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>		<b>Unit</b>
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>	
Clock period	$T_{CY}$	2.5		2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125		1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125		1.323		ns
Pipelined clock period	$T_{PLCY}$	2.5		2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125		1.323		ns
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125		1.323		ns
Read access time with pipeline register			0.334		0.393	ns
Read access time without pipeline register	$T_{CLK2Q}$		2.273		2.674	ns
Access time with feed-through write timing			1.529		1.799	ns
Address setup time	$T_{ADDRSU}$	0.441		0.519		ns
Address hold time	$T_{ADDRHD}$	0.274		0.322		ns
Data setup time	$T_{DSU}$	0.341		0.401		ns
Data hold time	$T_{DHD}$	0.107		0.126		ns
Block select setup time	$T_{BLKSU}$	0.207		0.244		ns

**Table 232 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 2K × 9 (continued)**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>		<b>Unit</b>
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>	
Address setup time	T <sub>ADDRSU</sub>	0.475		0.559		ns
Address hold time	T <sub>ADDRHD</sub>	0.274		0.322		ns
Data setup time	T <sub>DSU</sub>	0.336		0.395		ns
Data hold time	T <sub>DHD</sub>	0.082		0.096		ns
Block select setup time	T <sub>BLKSU</sub>	0.207		0.244		ns
Block select hold time	T <sub>BLKHD</sub>	0.216		0.254		ns
Block select to out disable time (when pipelined register is disabled)	T <sub>BLK2Q</sub>		1.529		1.799	ns
Block select minimum pulse width	T <sub>BLKMPW</sub>	0.186		0.219		ns
Read enable setup time	T <sub>RDESU</sub>	0.485		0.57		ns
Read enable hold time	T <sub>RDEHD</sub>	0.071		0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	T <sub>RDPLESU</sub>	0.248		0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	T <sub>RDPLEHD</sub>	0.102		0.12		ns
Asynchronous reset to output propagation delay	T <sub>R2Q</sub>		1.514		1.781	ns
Asynchronous reset removal time	T <sub>RSTREM</sub>	0.506		0.595		ns
Asynchronous reset recovery time	T <sub>RSTREC</sub>	0.004		0.005		ns
Asynchronous reset minimum pulse width	T <sub>RSTMPW</sub>	0.301		0.354		ns
Pipelined register asynchronous reset removal time	T <sub>PLRSTREM</sub>	-0.279		-0.328		ns
Pipelined register asynchronous reset recovery time	T <sub>PLRSTREC</sub>	0.327		0.385		ns
Pipelined register asynchronous reset minimum pulse width	T <sub>PLRSTMPW</sub>	0.282		0.332		ns
Synchronous reset setup time	T <sub>SRSTSU</sub>	0.226		0.265		ns
Synchronous reset hold time	T <sub>SRSTHD</sub>	0.036		0.043		ns
Write enable setup time	T <sub>WESU</sub>	0.415		0.488		ns
Write enable hold time	T <sub>WEHD</sub>	0.048		0.057		ns
Maximum frequency	F <sub>MAX</sub>		400		340	MHz

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 4K × 4 in worst commercial-case conditions when T<sub>J</sub> = 85 °C, V<sub>DD</sub> = 1.14 V.

**Table 233 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 4K × 4**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>		<b>Unit</b>
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>	
Clock period	T <sub>CY</sub>	2.5		2.941		ns
Clock minimum pulse width high	T <sub>CLKMPWH</sub>	1.125		1.323		ns
Clock minimum pulse width low	T <sub>CLKMPWL</sub>	1.125		1.323		ns
Pipelined clock period	T <sub>PLCY</sub>	2.5		2.941		ns
Pipelined clock minimum pulse width high	T <sub>PLCLKMPWH</sub>	1.125		1.323		ns

**Table 233 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 4K × 4 (continued)**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Pipelined clock minimum pulse width low	T <sub>PLCLKMPWL</sub>	1.125		1.323		ns
Read access time with pipeline register			0.323		0.38	ns
Read access time without pipeline register	T <sub>CLK2Q</sub>		2.273		2.673	ns
Access time with feed-through write timing			1.511		1.778	ns
Address setup time	T <sub>ADDRSU</sub>	0.543		0.638		ns
Address hold time	T <sub>ADDRHD</sub>	0.274		0.322		ns
Data setup time	T <sub>DSU</sub>	0.334		0.393		ns
Data hold time	T <sub>DHD</sub>	0.082		0.096		ns
Block select setup time	T <sub>BLKSU</sub>	0.207		0.244		ns
Block select hold time	T <sub>BLKHD</sub>	0.216		0.254		ns
Block select to out disable time (when pipelined register is disabled)	T <sub>BLK2Q</sub>		1.511		1.778	ns
Block select minimum pulse width	T <sub>BLKMPW</sub>	0.186		0.219		ns
Read enable setup time	T <sub>RDESU</sub>	0.516		0.607		ns
Read enable hold time	T <sub>RDEHD</sub>	0.071		0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	T <sub>RDPLESU</sub>	0.248		0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	T <sub>RDPLEHD</sub>	0.102		0.12		ns
Asynchronous reset to output propagation delay	T <sub>R2Q</sub>		1.507		1.773	ns
Asynchronous reset removal time	T <sub>RSTREM</sub>	0.506		0.595		ns
Asynchronous reset recovery time	T <sub>RSTREC</sub>	0.004		0.005		ns
Asynchronous reset minimum pulse width	T <sub>RSTMPW</sub>	0.301		0.354		ns
Pipelined register asynchronous reset removal time	T <sub>PLRSTREM</sub>	-0.279		-0.328		ns
Pipelined register asynchronous reset recovery time	T <sub>PLRSTREC</sub>	0.327		0.385		ns
Pipelined register asynchronous reset minimum pulse width	T <sub>PLRSTMPW</sub>	0.282		0.332		ns
Synchronous reset setup time	T <sub>SRSTSU</sub>	0.226		0.265		ns
Synchronous reset hold time	T <sub>SRSTHD</sub>	0.036		0.043		ns
Write enable setup time	T <sub>WESU</sub>	0.458		0.539		ns
Write enable hold time	T <sub>WEHD</sub>	0.048		0.057		ns
Maximum frequency	F <sub>MAX</sub>		400		340	MHz

**Table 239 • μSRAM (RAM128x9) in 128 × 9 Mode (continued)**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>	
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>
Read asynchronous reset removal time (pipelined clock)		-0.023		-0.027	ns
Read asynchronous reset removal time (non-pipelined clock)	$T_{RSTREM}$	0.046		0.054	ns
Read asynchronous reset recovery time (pipelined clock)		0.507		0.597	ns
Read asynchronous reset recovery time (non-pipelined clock)	$T_{RSTREC}$	0.236		0.278	ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	$T_{R2Q}$		0.835		0.982 ns
Read synchronous reset setup time	$T_{SRSTSU}$	0.271		0.319	ns
Read synchronous reset hold time	$T_{SRSTHD}$	0.061		0.071	ns
Write clock period	$T_{CCY}$	4		4	ns
Write clock minimum pulse width high	$T_{CCLKMPWH}$	1.8		1.8	ns
Write clock minimum pulse width low	$T_{CCLKMPWL}$	1.8		1.8	ns
Write block setup time	$T_{BLKCSU}$	0.404		0.476	ns
Write block hold time	$T_{BLKCHD}$	0.007		0.008	ns
Write input data setup time	$T_{DINCSU}$	0.115		0.135	ns
Write input data hold time	$T_{DINCHD}$	0.15		0.177	ns
Write address setup time	$T_{ADDRCSU}$	0.088		0.104	ns
Write address hold time	$T_{ADDRCHD}$	0.128		0.15	ns
Write enable setup time	$T_{WECSU}$	0.397		0.467	ns
Write enable hold time	$T_{WECHD}$	-0.026		-0.03	ns
Maximum frequency	$F_{MAX}$		250		250 MHz

The following table lists the μSRAM in 128 × 8 mode in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 240 • μSRAM (RAM128x8) in 128 × 8 Mode**

<b>Parameter</b>	<b>Symbol</b>	<b>-1</b>		<b>-Std</b>	
		<b>Min</b>	<b>Max</b>	<b>Min</b>	<b>Max</b>
Read clock period	$T_{CY}$	4		4	ns
Read clock minimum pulse width high	$T_{CLKMPWH}$	1.8		1.8	ns
Read clock minimum pulse width low	$T_{CLKMPWL}$	1.8		1.8	ns
Read pipeline clock period	$T_{PLCY}$	4		4	ns
Read pipeline clock minimum pulse width high	$T_{PLCLKMPWH}$	1.8		1.8	ns
Read pipeline clock minimum pulse width low	$T_{PLCLKMPWL}$	1.8		1.8	ns
Read access time with pipeline register			0.266		0.313 ns
Read access time without pipeline register	$T_{CLK2Q}$		1.677		1.973 ns
Read address setup time in synchronous mode		0.301		0.354	ns
Read address setup time in asynchronous mode	$T_{ADDRSU}$	1.856		2.184	ns

**Table 265 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric Only)**

M2S/M2GL Device	Auto Programming 100 kHz	Auto Update 25 MHz	Programming Recovery 12.5 MHz	Unit
005	69	49	50	Sec
010	99	57	57	Sec
025	150	64	63	Sec
050	55 <sup>1</sup>	Not Supported	Not Supported	Sec
060	313	105	104	Sec
090	449	131	130	Sec
150	730	179	183	Sec

1. Auto programming in 050 device is done through SC\_SPI, and SPI CLK is set to 6.25 MHz.

**Table 266 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (eNVM Only)**

M2S/M2GL Device	Auto Programming 100 kHz	Auto Update 25 MHz	Programming Recovery 12.5 MHz	Unit
005	63	70	71	Sec
010	108	109	109	Sec
025	109	107	108	Sec
050	107	Not Supported	Not Supported	Sec
060	100	108	108	Sec
090	176	184	184	Sec
150	183	183	183	Sec

**Table 267 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric and eNVM)**

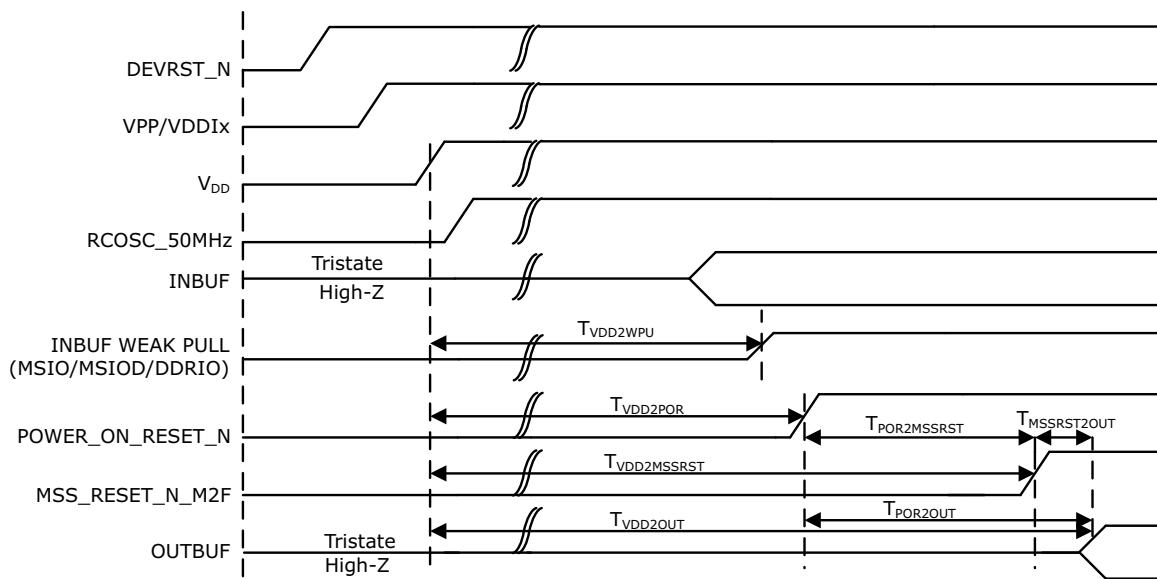
M2S/M2GL Device	Auto Programming 100 kHz	Auto Update 25 MHz	Programming Recovery 12.5 MHz	Unit
005	109	89	88	Sec
010	183	135	135	Sec
025	251	142	143	Sec
050	134	Not Supported	Not Supported	Sec
060	390	183	180	Sec
090	604	283	282	Sec
150	889	331	332	Sec

### 2.3.21 Clock Conditioning Circuits (CCC)

The following table lists the CCC/PLL specifications in worst-case industrial conditions when  $T_J = 100^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 282 • IGLOO2 and SmartFusion2 SoC FPGAs CCC/PLL Specification**

Parameter	Min	Typ	Max	Unit	Conditions
Clock conditioning circuitry input frequency $F_{IN\_CCC}$	1 0.032	200	200	MHz	All CCC 32 kHz capable CCC
Clock conditioning circuitry output frequency $F_{OUT\_CCC}$ <sup>1</sup>	0.078	400	400	MHz	
PLL VCO frequency <sup>2</sup>	500	1000	1000	MHz	
Delay increments in programmable delay blocks	75	100	100	ps	
Number of programmable values in each programmable delay block		64			
Acquisition time	70 1	100 16	100 ms	μs ms	$F_{IN} \geq 1\text{ MHz}$ $F_{IN} = 32\text{ kHz}$
Input duty cycle (reference clock)					Internal Feedback
	10	90	90	%	$1\text{ MHz} \leq F_{IN\_CCC} \leq 25\text{ MHz}$
	25	75	75	%	$25\text{ MHz} \leq F_{IN\_CCC} \leq 100\text{ MHz}$
	35	65	65	%	$100\text{ MHz} \leq F_{IN\_CCC} \leq 150\text{ MHz}$
	45	55	55	%	$150\text{ MHz} \leq F_{IN\_CCC} \leq 200\text{ MHz}$
					External Feedback (CCC, FPGA, Off-chip)
	25	75	75	%	$1\text{ MHz} \leq F_{IN\_CCC} \leq 25\text{ MHz}$
	35	65	65	%	$25\text{ MHz} \leq F_{IN\_CCC} \leq 35\text{ MHz}$
	45	55	55	%	$35\text{ MHz} \leq F_{IN\_CCC} \leq 50\text{ MHz}$
Output duty cycle	48	52	52	%	050 devices $F_{OUT} \leq 400\text{ MHz}$
	48	52	52	%	005, 010, and 025 devices $F_{OUT} < 350\text{ MHz}$
	46	54	54	%	005, 010, and 025 devices $350\text{ MHz} \leq F_{out} \leq 400\text{ MHz}$
	48	52	52	%	060 and 090 devices $F_{OUT} \leq 100\text{ MHz}$
	44	52	52	%	060 and 090 devices $100\text{ MHz} \leq F_{OUT} \leq 400\text{ MHz}$
	48	52	52	%	150 devices $F_{OUT} \leq 120\text{ MHz}$
	45	52	52	%	150 devices $120\text{ MHz} \leq F_{OUT} \leq 400\text{ MHz}$
<b>Spread Spectrum Characteristics</b>					
Modulation frequency range	25	35	50	k	
Modulation depth range	0	1.5	1.5	%	
Modulation depth control		0.5	0.5	%	

**Figure 17 • Power-up to Functional Timing Diagram for SmartFusion2**

The following table lists the IGLOO2 power-up to functional times in worst-case industrial conditions when  $T_J = 100^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 289 • Power-up to Functional Times for IGLOO2**

Symbol	From	To	Description	Maximum Power-up to Functional Time for IGLOO2 (μs)						
				005	010	025	050	060	090	150
$T_{POR2OUT}$	POWER_ON_RESET_N	Output available at I/O	Fabric to output	114	114	114	113	114	114	114
$T_{VDD2OUT}$	$V_{DD}$	Output available at I/O	$V_{DD}$ at its minimum threshold level to output	2587	2600	2607	2558	2591	2600	2699
$T_{VDD2POR}$	$V_{DD}$	POWER_ON_RESET_N	$V_{DD}$ at its minimum threshold level to fabric	2474	2486	2493	2445	2477	2486	2585
$T_{VDD2WPU}$	DEVRST_N	DDRIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	2500	2487	2509	2475	2507	2519	2617
	DEVRST_N	MSIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	2504	2491	2510	2478	2517	2525	2620
	DEVRST_N	MSIOD Inbuf weak pull	DEVRST_N to Inbuf weak pull	2479	2468	2493	2458	2486	2499	2595

**Note:** For more information about power-up times, see [UG0448: IGLOO2 FPGA High Performance Memory Subsystem User Guide](#).

The following table lists the IGLOO2 DEVRST\_N to functional times in worst-case industrial conditions when  $T_J = 100^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 292 • DEVRST\_N to Functional Times for IGLOO2**

<b>Symbol</b>	<b>From</b>	<b>To</b>	<b>Description</b>	<b>Maximum Power-up to Functional Time for IGLOO2 (μs)</b>							
				<b>005</b>	<b>010</b>	<b>025</b>	<b>050</b>	<b>060</b>	<b>090</b>	<b>150</b>	
$T_{POR2OUT}$	POWER_ON _RESET_N	Output available at I/O	Fabric to output	114	116	113	113	115	115	114	
$T_{DEVRST2OUT}$	DEVRST_N	Output available at I/O	$V_{DD}$ at its minimum threshold level to output	314	353	314	307	343	341	341	
$T_{DEVRST2POR}$	DEVRST_N	POWER_O N_RESET_ N	$V_{DD}$ at its minimum threshold level to fabric	200	238	201	195	230	229	227	
$T_{DEVRST2WPU}$	DEVRST_N	DDRIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215	
	DEVRST_N	MSIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215	
	DEVRST_N	MSIOD Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215	

### 2.3.31.3 Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given are for a 35 pF load on the pins and all sequential timing characteristics are related to SPI\_x\_CLK. For timing parameter definitions, see [Figure 22](#), page 128.

The following table lists the SPI characteristics in worst-case industrial conditions when  $T_J = 100^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$

**Table 305 • SPI Characteristics for All Devices**

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPIFMAX	Maximum operating frequency of SPI interface			20	MHz	
sp1	SPI_[0 1]_CLK minimum period					
	SPI_[0 1]_CLK = PCLK/2	12			ns	
	SPI_[0 1]_CLK = PCLK/4	24.1			ns	
	SPI_[0 1]_CLK = PCLK/8	48.2			ns	
	SPI_[0 1]_CLK = PCLK/16	0.1			μs	
	SPI_[0 1]_CLK = PCLK/32	0.19			μs	
	SPI_[0 1]_CLK = PCLK/64	0.39			μs	
	SPI_[0 1]_CLK = PCLK/128	0.77			μs	
sp2	SPI_[0 1]_CLK minimum pulse width high					
	SPI_[0 1]_CLK = PCLK/2	6			ns	
	SPI_[0 1]_CLK = PCLK/4	12.05			ns	
	SPI_[0 1]_CLK = PCLK/8	24.1			ns	
	SPI_[0 1]_CLK = PCLK/16	0.05			μs	
	SPI_[0 1]_CLK = PCLK/32	0.095			μs	
	SPI_[0 1]_CLK = PCLK/64	0.195			μs	
	SPI_[0 1]_CLK = PCLK/128	0.385			μs	
sp3	SPI_[0 1]_CLK minimum pulse width low					
	SPI_[0 1]_CLK = PCLK/2	6			ns	
	SPI_[0 1]_CLK = PCLK/4	12.05			ns	
	SPI_[0 1]_CLK = PCLK/8	24.1			ns	
	SPI_[0 1]_CLK = PCLK/16	0.05			μs	
	SPI_[0 1]_CLK = PCLK/32	0.095			μs	
	SPI_[0 1]_CLK = PCLK/64	0.195			μs	
	SPI_[0 1]_CLK = PCLK/128	0.385			μs	
sp4	SPI_[0 1]_CLK, SPI_[0 1]_DO, SPI_[0 1]_SS rise time (10%– 90%) <sup>1</sup>		2.77		ns	I/O Configuration: LVCMS 2.5 V– 8 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C

**Table 310 • SPI Characteristics for All Devices (continued)**

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPI master configuration (applicable for 060, 090, and 150 devices)						
sp6m	SPI_[0 1]_DO setup time <sup>2</sup>	(SPI_x_CLK_period/2) – 7.0			ns	
sp7m	SPI_[0 1]_DO hold time <sup>2</sup>	(SPI_x_CLK_period/2) – 9.5			ns	
sp8m	SPI_[0 1]_DI setup time <sup>2</sup>	15			ns	
sp9m	SPI_[0 1]_DI hold time <sup>2</sup>	–2.5			ns	
SPI slave configuration (applicable for 060, 090, and 150 devices)						
sp6s	SPI_[0 1]_DO setup time <sup>2</sup>	(SPI_x_CLK_period/2) – 16.0			ns	
sp7s	SPI_[0 1]_DO hold time <sup>2</sup>	(SPI_x_CLK_period/2) - 3.5			ns	
sp8s	SPI_[0 1]_DI setup time <sup>2</sup>	3			ns	
sp9s	SPI_[0 1]_DI hold time <sup>2</sup>	2.5			ns	

1. For specific Rise/Fall Times board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>.
2. For allowable pcik configurations, see the Serial Peripheral Interface Controller section in the *UG0331: SmartFusion2 Microcontroller Subsystem User Guide*.

**Figure 23 • SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1)**